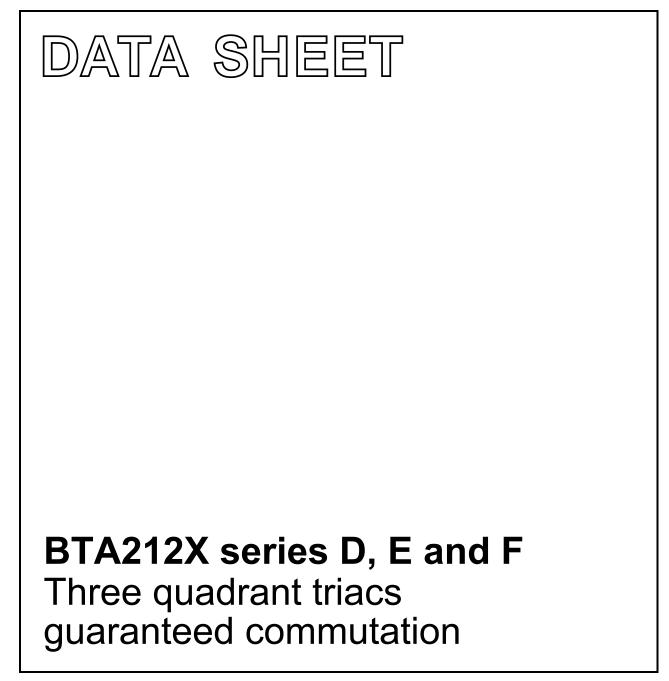
DISCRETE SEMICONDUCTORS



Product specification

June 2003



MAX.

800E

800

12

95

UNIT

٧

А

А

T1

G

# Three quadrant triacs guaranteed commutation

# BTA212X series D, E and F

MAX.

600D

600E

600F

600

12

95

## GENERAL DESCRIPTION

Passivated guaranteed commutation triacs in a full pack, plastic envelope intended for use in motor control circuits or with other highly inductive loads. These devices balance the of requirements commutation performance and gate sensitivity. The "sensitive gate" E series and "logic level" D series are intended for interfacing with low power drivers, including micro controllers.

### **PINNING - SOT186A**

# PIN CONFIGURATION

SYMBOL

V<sub>DRM</sub>

T(RMS)

ITSM

QUICK REFERENCE DATA

current

PARAMETER

Repetitive peak off-state

Non-repetitive peak on-state

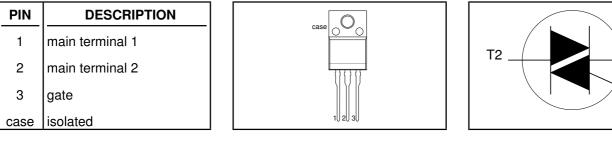
voltages RMS on-state current

### SYMBOL

**BTA212X-**

**BTA212X-**

**BTA212X-**



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MA	Х.	UNIT
$V_{DRM}$	Repetitive peak off-state voltages		-	<b>-600</b> 600 <sup>1</sup>	<b>-800</b> 800	v
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>hs</sub> ≤56 °C	-	12	2	A
I <sub>TSM</sub>	Non-repetitive peak on-state current	full sine wave; $T_j = 25 \degree C$ prior to surge				
		t = 20 ms t = 16.7 ms	-	95 10		A A
l²t dl⊤/dt	I <sup>2</sup> t for fusing Repetitive rate of rise of on-state current after		-	45 10		A²s A∕µs
I <sub>GM</sub> P <sub>GM</sub>	triggering Peak gate current Peak gate power		-	25		A W
P <sub>G(AV)</sub>	Average gate power	over any 20 ms period	-	0.8	5	W
T <sub>stg</sub> T <sub>j</sub>	Storage temperature Operating junction temperature		-40 -	15 12		°C °C

<sup>1</sup> Although not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15  $A/\mu s$ .

# Three quadrant triacs guaranteed commutation

# BTA212X series D, E and F

## **ISOLATION LIMITING VALUE & CHARACTERISTIC**

 $T_{hs} = 25$  °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>isol</sub>	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	-	-	2500	V
C <sub>isol</sub>	Capacitance from T2 to external heatsink	f = 1 MHz	-	10	-	pF

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-hs</sub> R <sub>th j-a</sub>	Thermal resistance junction to heatsink Thermal resistance junction to ambient	full or half cycle with heatsink compound without heatsink compound in free air	- - -	- - 55	4.0 5.5 -	K/W K/W K/W

## STATIC CHARACTERISTICS

### $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT	
		BTA212X-		D	E	F	
I <sub>GT</sub>	Gate trigger current <sup>2</sup>	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}$ T2+ G+ T2+ G-	- -	5 5 5	10 10	25 25	mA mA
I <sub>L</sub>	Latching current	T2- G- V <sub>D</sub> = 12 V; I <sub>GT</sub> = 0.1 A T2+ G+ T2+ G- T2- G-		5 15 25 25	10 25 30 30	25 30 40 40	mA mA mA mA
I <sub>H</sub>	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	15	25	30	mA
V <sub>T</sub> V <sub>GT</sub>	On-state voltage Gate trigger voltage		- - 0.25	1.6 1.5 -		V V V	
I <sub>D</sub>	Off-state leakage current	$V_{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125 ^{\circ}{\rm C}$	-	0.5		mA	

<sup>2</sup> Device does not trigger in the T2-, G+ quadrant.

# Three quadrant triacs guaranteed commutation

# BTA212X series D, E and F

## **DYNAMIC CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

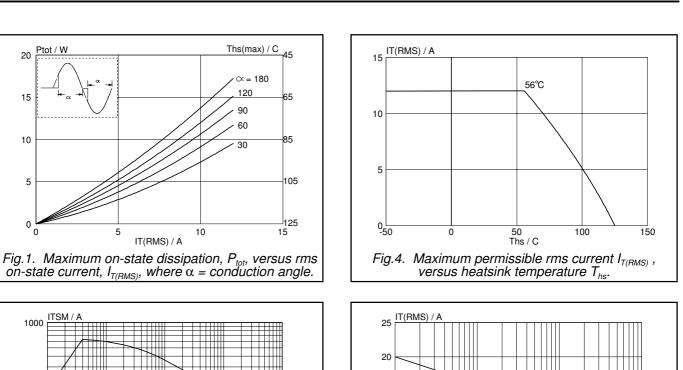
SYMBOL	PARAMETER	CONDITIONS	MIN.			MAX.	UNIT
		BTA212X-	D	E	F		
dV <sub>D</sub> /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)};$ $T_j = 110$ °C; exponential waveform; gate open	30	60	70	-	V/µs
dl <sub>com</sub> /dt	Critical rate of change of commutating current	circuit $V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 ^{\circ}\text{C};$ $I_{T(RMS)} = 12 \text{ A};$ $dV_{com}/dt = 10 \text{ V/}\mu\text{s}; \text{ gate}$ open circuit	1.0	8.0	21	-	A/ms
dl <sub>com</sub> /dt	Critical rate of change of commutating current	$\begin{array}{l} V_{\text{DM}} = 400 \; V; \; T_{j} = 125 \; ^{\circ}\text{C}; \\ I_{\text{T(RMS)}} = 12 \; \text{A}; \\ dV_{\text{com}}/dt = 0.1 \; V/\mu\text{s}; \; \text{gate} \\ \text{open circuit} \end{array}$	3.5	16	32	-	A/ms

BTA212X series D, E and F

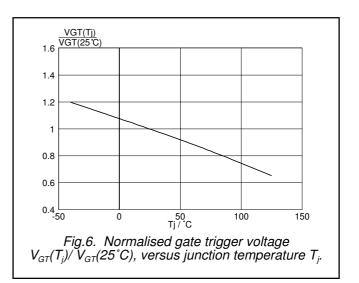
# Three quadrant triacs guaranteed commutation

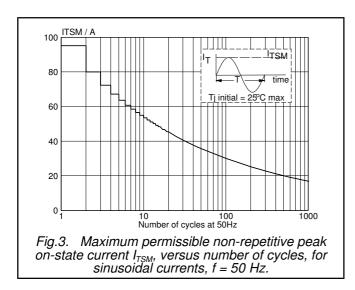
5

IT(RMS) / A



# 15 10 5 0.01 0.1 10 surge duration / s Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$ , versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{hs} \le 56$ °C.





10

initial = 25°C

10ms

100ms

1ms

T/s

Fig.2. Maximum permissible non-repetitive peak on-state current  $I_{TSM}$ , versus pulse width  $t_p$ , for sinusoidal currents,  $t_p \le 20ms$ .

Ptot / W 20

15

10

5

0

n

1000

100

10 L 10us

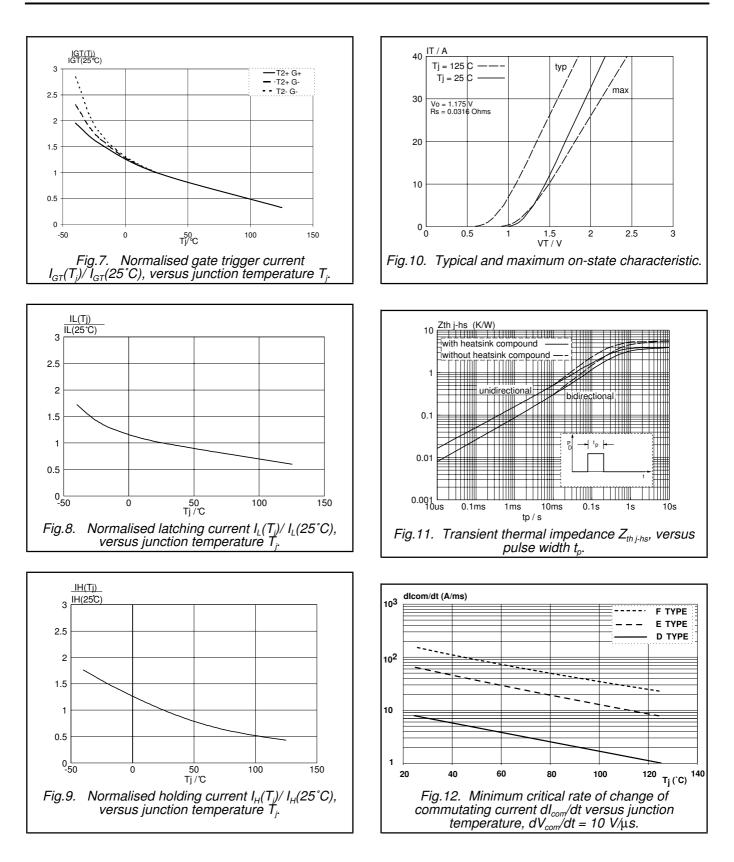
ITSM / A

/dt limi

100us

BTA212X series D, E and F

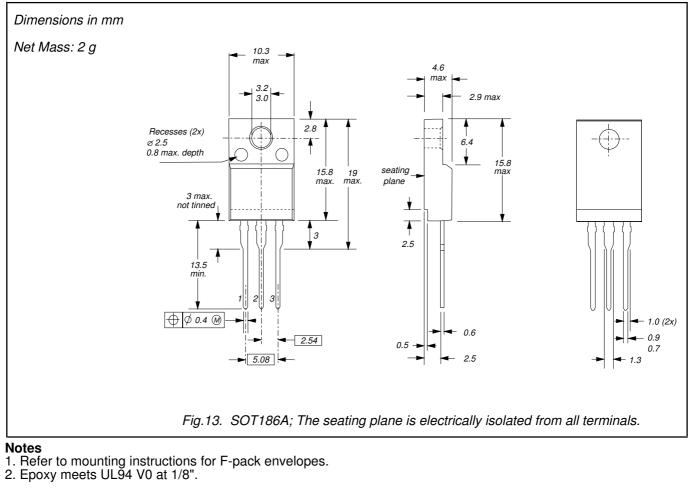
# Three quadrant triacs guaranteed commutation



BTA212X series D, E and F

# Three quadrant triacs guaranteed commutation

# **MECHANICAL DATA**



# Legal information

### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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